

TOSHIBA DIODE SILICON EPITAXIAL SCHOTTKY BARRIER TYPE

HN2S01FU

LOW VOLTAGE HIGH SPEED SWITCHING APPLICATION

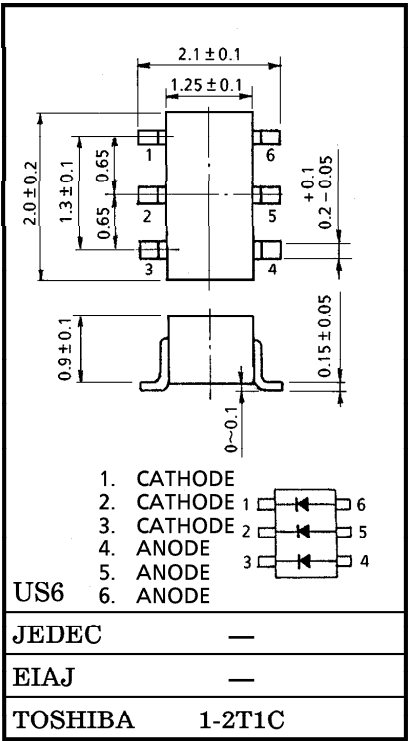
Unit in mm

- HN2S01F is composed of 3 independent diodes.
- Low Forward Voltage :  $V_F=0.23V$  (TYP.) @  $I_F=5mA$

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum (Peak) Reverse Voltage	$V_{RM}$	15	V
Reverse Voltage	$V_R$	10	V
Maximum (Peak) Forward Current	$I_{FM}$	200*	mA
Average Forward Current	$I_O$	100*	mA
Surge Current (10ms)	$I_{FSM}$	1*	A
Power Dissipation	P	200	mW
Junction Temperature	$T_j$	125	°C
Storage Temperature Range	$T_{stg}$	-55~125	°C
Operating Temperature Range	$T_{opr}$	-40~100	°C

\* : This is the Maximum Ratings of single diode (Q1 or Q2 or Q3).  
In the case of using 2 or 3 diodes, the Maximum Ratings per diode is 75% of the single diode one.

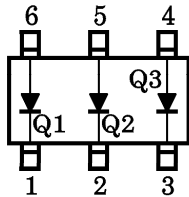


Weight : 6.2mg

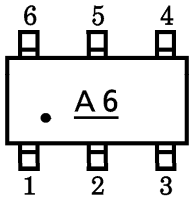
ELECTRICAL CHARACTERISTICS (Q1, Q2, Q3 COMMON Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage	$V_F$ (1)	$I_F=1mA$	—	0.18	—	V
	$V_F$ (2)	$I_F=5mA$	—	0.23	0.30	
	$V_F$ (3)	$I_F=100mA$	—	0.35	0.50	
Reverse Current	$I_R$	$V_R=10V$	—	—	20	$\mu A$
Total Capacitance	$C_T$	$V_R=0, f=1MHz$	—	20	40	pF

PIN ASSIGNMENT (TOP VIEW)



MARKING



961001EAA2

- TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

